SUP70101EL

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Vishay Siliconix

S

TO-220AB

PRODUCT SUMMARY						
V _{DS} (V)	-100					
$R_{DS(on)}$ max. (Ω) at V_{GS} = -10 V	0.0101					
$R_{DS(on)}$ max. (Ω) at V_{GS} = -4.5 V	0.0150					
Q _g typ. (nC)	125					
I _D (A)	-120					
Configuration	Single					

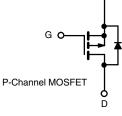
FEATURES

P-Channel 100 V (D-S) 175 °C MOSFET

- TrenchFET[®] power MOSFET
- · Package with low thermal resistance
- Maximum 175 °C junction temperature
- Low R_{DS(on)} minimizes power loss from conduction
 FREE
- · Compatible with logic-level gate driving
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · Battery protection
- Motor drive control
- Load switch



ORDERING INFORMATION	
Package	TO-220AB
Lead (Pb)-free and halogen-free	SUP70101EL-GE3

ABSOLUTE MAXIMUM RATINGS ($T_C = 25 \degree C$, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	-100		
Gate-source voltage		V _{GS}	± 20	V	
Continuous drain current ^d	T _C = 25 °C		-120		
(T _J = 175 °C)	T _C = 125 °C	I _D	-78		
Pulsed drain current (100 µs)		I _{DM}	-240	A	
Avalanche current	L = 0.1 mH	I _{AS}	-75		
Single pulse avalanche energy ^a		E _{AS}	281	mJ	
Power dissigntion	T_{C} = 25 °C °	Р	375	w	
	T _C = 125 °C ^b	P _D -	125		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	TYPICAL	UNIT
Junction-to-ambient	PCB mount ^b	R _{thJA}	40	°C/W
Junction-to-case		R _{thJC}	0.4	0/10

Notes

a. Duty cycle \leq 1 %

b. When mounted on 1" square PCB (FR4 material)

c. See SOA curve for voltage derating

d. Limited by package

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COMPLIANT

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PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 V, I_D = -250 \mu A$	-100	-	-	V	
Gate threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	-1.5	-	-2.5	v	
Gate-body leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$	-	-	± 100	nA	
		$V_{DS} = -100 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	-	-	-1	μΑ	
Zero gate voltage drain current	I _{DSS}	V_{DS} = -100 V, V_{GS} = 0 V, T_{J} = 125 °C	-	-	-50		
		V_{DS} = -100 V, V_{GS} = 0 V, T_{J} = 175 °C	-	-	-250		
On-state drain current ^a	I _{D(on)}	$V_{DS} \leq$ -5 V, V_{GS} = -10 V	-120	-	-	А	
Drain-source on-state resistance ^a	Para	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -30 \text{ A}$	-	0.0081	0.0101	Ω	
Drain-source on-state resistance -	R _{DS(on)}	V_{GS} = -4.5 V, I _D = -20 A	-	0.0114	0.0150		
Forward transconductance a	g fs	V _{DS} = -15 V, I _D = -25 A	-	60	-	S	
Dynamic ^b							
Input capacitance	C _{iss}		-	7000	-	pF	
Output capacitance	C _{oss}	V_{GS} = 0 V, V_{DS} = -50 V, f = 1 MHz	-	2180	-		
Reverse transfer capacitance	C _{rss}		-	170	-		
Total gate charge ^c	Qg		-	125	190	nC	
Gate-source charge ^c	Q _{gs}	$V_{DS} = -50 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -110 \text{ A}$	-	29	-		
Gate-drain charge ^c	Q _{gd}		-	30	-		
Gate resistance	Rg	f = 1 MHz	1.3	6.5	13	Ω	
Turn-on delay time ^c	t _{d(on)}		-	20	30		
Rise time ^c	t _r	V_{DD} = -50 V, R_L = 0.71 Ω	-	40	60	ns	
Turn-off delay time ^c	t _{d(off)}	$I_D\cong$ -70 A, V_{GEN} = -10 V, R_g = 1 Ω	-	110	200		
Fall time ^c	t _f		-	40	60		
Drain-Source Body Diode Characte	r istics (T _C = 25	o °C ^b)					
Continuous current	I _S		-	-	-110	А	
Pulsed current	I _{SM}		-	-	-240	~	
Forward voltage ^a	V _{SD}	$I_F = -85 \text{ A}, V_{GS} = 0 \text{ V}$	-	-1	-1.5	V	
Reverse recovery time	t _{rr}		-	110	170	ns	
Peak reverse recovery charge	I _{RM(REC)}	I _F = -85 A, dl/dt = 100 A/µs	-	-7	-11	А	
Reverse recovery charge	Q _{rr}		-	0.38	0.57	μC	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

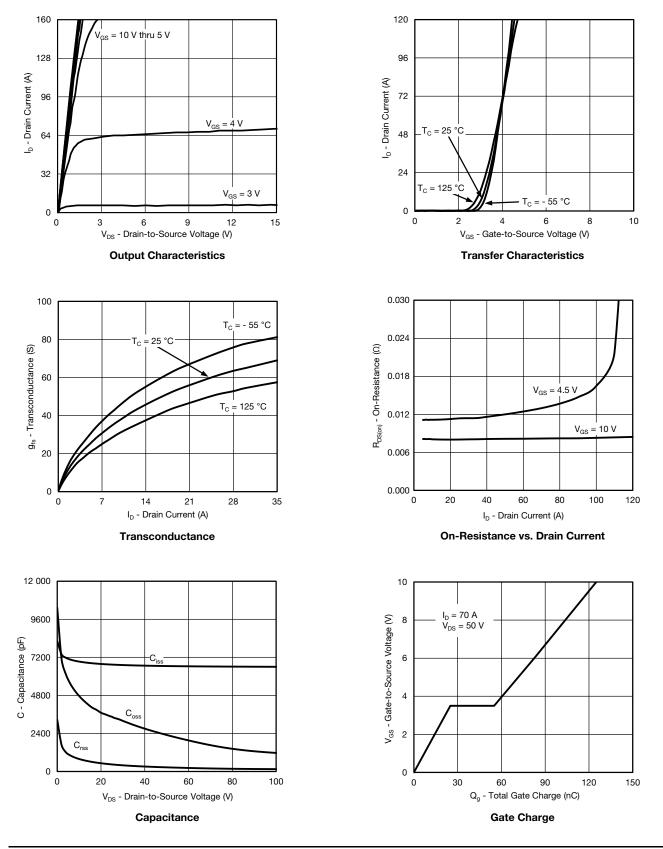
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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



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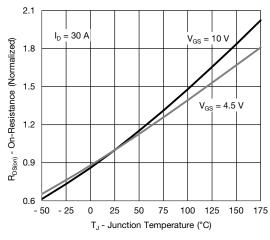
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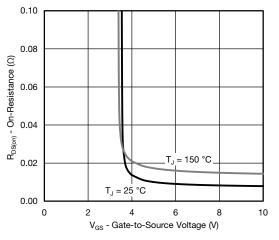
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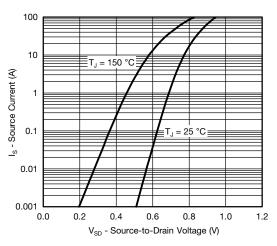
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



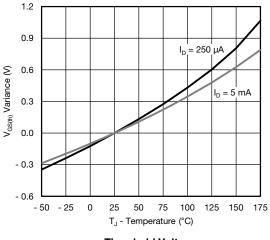
On-Resistance vs. Junction Temperature



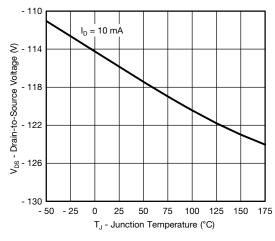
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage







Drain Source Breakdown vs. Junction Temperature

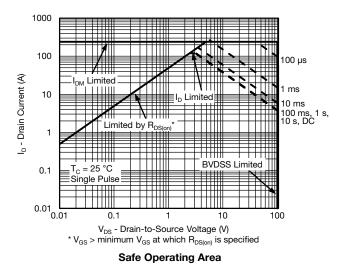
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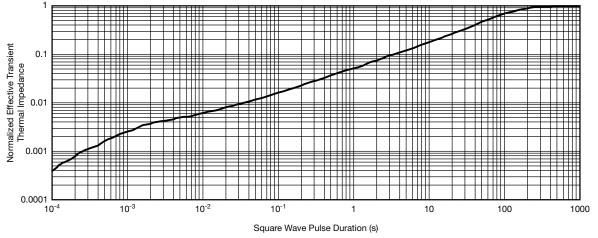
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)





Normalized Thermal Transient Impedance, Junction-to-Ambient

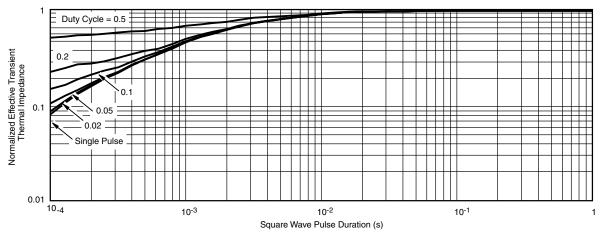




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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

• The characteristics shown in the two graphs

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- Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction to Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?77632.

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	MILLIMETERS		INC	HES	
DIM.	MIN.	MAX.	MIN.	MAX.	
А	4.25	4.65	0.167	0.183	
b	0.69	1.01	0.027	0.040	
b(1)	1.20	1.73	0.047	0.068	
С	0.36	0.61	0.014	0.024	
D	14.85	15.49	0.585	0.610	
D2	12.19	12.70	0.480	0.500	
E	10.04	10.51	0.395	0.414	
е	2.41	2.67	0.095	0.105	
e(1)	4.88	5.28	0.192	0.208	
F	1.14	1.40	0.045	0.055	
H(1)	6.09	6.48	0.240	0.255	
J(1)	2.41	2.92	0.095	0.115	
L	13.35	14.02	0.526	0.552	
L(1)	3.32	3.82	0.131	0.150	
ØР	3.54	3.94	0.139	0.155	
Q	2.60	3.00	0.102	0.118	
	0413-Rev. P,		0.102	0.118	

Note

 * M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM



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